



USB3.1, USB3.0 and USB2.0 Combo Switch

Features

- → 1:2 mux/demux for USB 3.1 Enhanced SS, USB 3.0 SS, 2.0HS, and 2.0FS signals
- → Switches Tx, Rx, and Dx from USB3.0 connector
- → Suitable for DisplayPort, PCIe Gen1/2/3, SATA 1.5/3/6G, SAS 1.5/3/6G and XAUI applications.
- → -3dB bandwidth for enhanced superspeed channel: 10.6GHz
- → Insertion Loss for enhanced superspeed channels @ 5.0 GHz: -1 5dB
- → Insertion Loss for superspeed channels @ 2.5 GHz: -0.9dB
- → Return loss for enhanced superspeed channels @ 5.0 GHz: -19.6dB
- → Return Loss for superspeed channels @ 2.5 GHz: -26.4dB
- → Low Bit-to-Bit Skew, 5ps typ(between '+' and '-' bits)
- → Low Crosstalk for enhanced superspeed channels: -31.1dB @ 5.0 GHz
- → Low Crosstalk for superspeed channels @2.5GHz: -33.3dB
- → Low Off Isolation for enhanced superspeed channels: -17.4dB @ 5.0 GHz
- → Low Off Isolation for superspeed channels @ 2.5GHz: -24.9dB
- → Insertion Loss for USB HS: -0.67dB @ 480Mbps
- → Crosstalk for USB HS: -33dB @ 480Mbps
- → Off Islation fo USB HS: -30dB @ 480Mbps
- → -3dB for USB HS: 1.4 GHz
- → V_{DD} Operating Range: 3.3V +/-10%
- → ESD Tolerance: 2kV HBM
- → Low channel-to-channel skew, 7ps typ
- → Packaging (Pb-free & Green):
 - ^o 32 TQFN (ZL) 3mm x 6mm x 0.75mm, 0.4mm pitch

Description

The PI3USB32212 USB3.1, USB3.0 and USB2.0 Combo Switch is a complete 1:2 switching solution for Enhanced SuperSpeed USB 3.1 signals. PI3USB32122 provides differential high-speed lanes for the USB3.1 10Gbps, USB3.0 5Gbps TX and RX lanes as well as a differential lane for 480 Mbps USB 2.0 signals.

PI3USB32212 can be used to connect two hosts to a single device or a single host to two devices.

PI3USB32212 offers excellent signal integrity for high-speed signals and low power dissipation. Insertion loss is -1.3dB and return loss is -19dB at 5 GHz (USB3.1). Insertion loss is -0.77dB and return loss is -27.8db at 2.5GHz (USB3.0).

Application

Routing of USB3.1/3.0/2.0 signals with low signal attenuation between source and sink. Applicable products include desktop PC, Notebook PC, Tablet, Docking, Telecom, DTV.







Pin Assignment (TQFN-32)



Truth Table

PD	ŌĒ	SEL1	SEL2	Function
0	X	0	Х	PortA is active fox Tx & Rx
0	Х	1	Х	PortB is active fox Tx & Rx
1	X	X	Х	Both ports are Hi_Z for Tx & Rx
X	1	X	X	Both ports are High_Z for D+/D-
1	1	X	Х	All channels are High_Z
X	0	X	0	PortB is active for D+/D-
X	0	X	1	PortA is active for D+/D-

Note:

PD & SEL1 are controls for the usb3.1 switch PD supports power down & output disable 1.

OE & SEL2 are controls for the usb2.0 switch 2.

Bottom metal plate can used as GND 3.

4. VDD at pin8 provides power to both top and bottom die

All VDD need to connect to power 5





Pin Description

Pin#	Pin Name	Signal Type	Description	
1	Tx+	I/O	Positive differential USB3.x Tx signal for COM port	
2	Tx-	I/O	Negative differential USB3.x Tx signal for COM port	
3	GND	Ground	Ground	
4	VDD	Power	3.3V +/-10% power supply	
5	Rx+	I/O	itive differential USB3.x Rx signal for COM port	
6	Rx-	I/O	gative differential USB3.x Rx signal for COM port	
7	SEL1	Ι	Control for USB 3.x	
8	VDD	Power	3.3V +/-10% power supply	
9	SEL2	Ι	Control for USB 2.0	
10	D+	I/O	Positive differential USB 2.0 COM port	
11	D-	I/O	Negative differential USB2.0 COM port	
12	GND	Ground	Ground	
13	GND	Ground	Ground	
14	D-B	I/O	Negative differential USB2.0 signal for port 1	
15	D+B	I/O	Positive differential USB2.0 signal for port 1	
16	GND	Ground	Ground	
17	D-A	I/O	Negative differential USB2.0 signal for port 0	
18	D+A	I/O	Positive differential USB2.0 signal for port 0	
19	ŌĒ	Ι	Control for USB 2.0	
20	GND	Ground	Ground	
21	Rx-B	I/O	Negative differential USB 3.x signal for port 0	
22	Rx+B	I/O	Positive differential USB 3.x signal for port 0	
23	Tx-B	I/O	Negative differential USB3.x Rx signal for port 0	
24	Tx+B	I/O	Positive differential USB3.x Tx signal for port 0	
25	GND	Ground	Ground	
26	Rx-A	I/O	Negative differential USB3.xRx signal for port 1	
27	Rx+A	I/O	Positive differential USB3.x Rx signal for port 1	
28	Tx-A	I/O	Negative differential USB3.x Rx signal for port 1	
29	Tx+A	I/O	Positive differential USB3.x Tx signal for port 1	
30	GND	Ground	Ground	
31	VDD	Power	3.3V +/-10% power supply	
32	PD	I	Power down and disable USB3.x output	





Maximum Ratings

(Above which useful life may be impaired. For user guidelines, not tested.)

Storage Temperature	65°C to +150°C
Supply Voltage to Ground Potential	-0.5V to +4.0V
DC Input Voltage, USB3	-0.5V to 1.5V
DC Input Voltage, USB2	–0.5V to V_{DD}
DC Output Current	120mA
Power Dissipation	0.5W
ESD	2KV HBM

Note: Stresses greater than those listed under MAXI-MUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

DC Electrical Characteristics for Switching over Operating Range

[IA = -40 C 10 + 65 C, VDD = 3.3V ±10/8]						
Parameter	Description	Test Conditions ⁽¹⁾	Min.	Typ.(1)	Max.	Units
V _{IH}	Input HIGH Voltage	Guaranteed HIGH level	0.65*V _{DD}			
VIL	Input LOW Voltage	Guaranteed LOW level			0.6	V
V _{IK}	Clamp Diode Voltage, Dx	$V_{DD} = Max., I_{IN} = -18mA$		-0.7	-1.2	
IIH	Input HIGH Current	$V_{DD} = Max., V_{IN} = V_{DD}$			±5	
IIL	Input LOW Current	V _{DD} = Max., V _{IN} = GND			±5	μΑ
R _{ON_SS}	On resistance between input to output for SuperSpeed signals	$V_{DD} = 3.3$ V, Vinput = 0V to 1V, I _{INPUT} = 20mA		10	13	Ohm
R _{ON_FS}	On resistance between input to output for USB2.0 FS signals (D+/D-)	$V_{DD} = 3.3V$, Vinput = 0 to 3.3V, I _{INPUT} = 20mA		7	9	Ohm
R _{ON_HS}	On resistance between input to output for USB2.0 HS signals (D+/D-)	V_{DD} = 3.3V, Vinput = -0.4V to +0.4V, I _{INPUT} = 20mA		4	6	Ohm

 $(TA - 40^{\circ}C + 25^{\circ}C)/DD - 33/(+10\%)$

Power Supply Characteristics (TA = $-40^{\circ}C$ to $+85^{\circ}C$)

Parameter	Description	Test Conditions ⁽¹⁾	Min.	Typ.(1)	Max.	Units
I _{CC}	Quiescent Power Supply Current	V_{DD} = Max., V_{IN} = GND or V_{DD}			500	μΑ





	iecifical characteristics over	Operain	ig kunge	$(1A = -40^{-1})$	10 +03°C	, vdd = 3.	$3^{\circ} \pm 10^{\circ}$
Parameter	Description	Test Conditions		Min.	Тур.	Max.	Units
		See Fig. 1 for	f= 2.5 GHz		-33.3		
DDXT	Differential Crosstalk on SuperSpeed	Measure-	f= 4.0 GHz		-31.9		
		ment Setup	f= 5.0 GHz		-31.1		σι
		See Fig. 2 for	f= 2.5 GHz		-24.9		uв
DDOI	Differential OFF Isolation on SuperSpeed	Measure-	f= 4.0 GHz		-18.9		
		ment Setup,	f= 5.0 GHz		-17.4		
		f= 2.5 GHz			-0.9		
DDIL	Differential Insertion Loss on SuperSpeed	f= 4.0 GHz			-1.3		dB
		f= 5.0 GHz			-1.5		
	Differential Return Loss on SuperSpeed channels	f= 2.5 GHz			-26.4		
R _{loss}		f= 4.0 GHz			-22.4		dB
		f= 5.0 GHz			-19.6		
BW	3db Bandwidth on SuperSpeed channels				10.6		GHz
			f= 240 MHz	-35	-39		- dB
X _{TALK-USB2} HS	Crosstalk	D 500	f= 825 MHz	-25	-28		
	OFF Isolation	$R_L = 50\Omega$	f= 240 MHz	-29	-32		
O _{IRR-USB2} HS			f= 825 MHz	-20	-23		
BW-USB2 HS	-3dB Bandwidth	$R_L = 50\Omega$		1100	1400		MHz
BW-USB2 HS	-0.5dB Bandwidth	$R_L = 50\Omega$		150	400		MHz
		f= 240 MHz			0.47	0.67	
		f= 825 MHz			1.8	2.4	dB
IN-USB2 HS	Insertion Loss	f= 1.0 GHz			2.2	2.6	
		f= 1.125 GHz			2.4	3.0	

namic Electrical Characteristics over Operatin 40° ta +85°C VDD 3.3V + 10%

Note:

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.

2. Typical values are at V_{DD} = 3.3V, T_A = 25°C ambient and maximum loading.

Switching Characteristics (T_A= -40° to +85°C, V_{DD} = 3.3V±10%)

Parameter	Description		Min.	Тур.	Max.	Units
T _{pd}		USB3		80		
	USB-HS			250		ps
t _{b-b}	Bit-to-bit skew within the same differential pair				10	ps
t _{ch-ch}	Channel-to-channel skew				20	ps
T _{sw}	Switching time between paths (toggling SEL1, SEL2)		2		100	ns







Fig 1. Crosstalk Setup



Fig 2. Off-isolation setup



Fig 3. Differential Insertion Loss set up







Fig 4. Differential Crosstalk - Super Speed



Fig 5. Differential Off Isolation - Super Speed







Fig 6. Differential Insertion Loss - Super Speed



Fig 7. Differential Return Loss – Super Speed







Fig 8. 12Gbps Eye without PI3USB32212



Fig 9. 12Gbps Eye with PI3USB32212







Fig 10. Differential Insertion loss, $V_{DD} = 3.3V - USB2 HS$





Test Circuit for Electrical Characteristics(1-5)



Notes:

- 1. C_L = Load capacitance: includes jig and probe capacitance.
- 2. R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator
- 3. Output 1 is for an output with internal conditions such that the output is low except when disabled by the output control.
- 4. Output 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- 5. All input impulses are supplied by generators having the following characteristics: PRR \leq MHz, $Z_{O} = 50\Omega$, $t_{R} \leq 2.5$ ns, $t_{F} \leq 2.5$ ns.
- 6. The outputs are measured one at a time with one transition per measurement.

Switching Waveforms



Voltage Waveforms Enable and Disable Times

Switch Positions

Test	Switch
t_{PLZ} , t_{PZL} (output on B-side)	2 * Vdd
t_{PHZ} , t_{PZH} (output on B-side)	GND
Prop Delay	Open

Test Circuit for Dynamic Electrical Characteristics







Packaging Mechanical: 32-TQFN (ZL)



For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

Ordering Information

Ordering Code	Package Code	Package Description
PI3USB32212ZLEX	ZL	32-contact, Very Thin Quad Flat No-Lead (TQFN) Copper Wire
PI3USB32212ZLEX+DA	ZL	32-contact, Very Thin Quad Flat No-Lead (TQFN) Gold Wire

Notes:

Thermal characteristics can be found on the company web site at www.diodes.com/design/support/packaging/ .

- E = Pb-free and Green
- X suffix = Tape/Reel





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